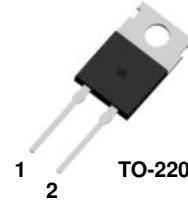


8A, 1200V Hyperfast Single Diode

Description

The AKF8H120ST is an hyperfast single diode, its typical reverse recovery time is 32ns. This device is designed for freewheel diode in motor and power switching applications, and specially suited for use in inverter welding.



1.Cathode 2.Anode

Features

- Hyperfast Soft Recovery: $t_{rr}=32\text{ns}$
- Typical Forward Voltage: $V_F=3.2\text{V} @ I_F=8\text{A}$
- Reverse Voltage: $V_{RRM}=1200\text{V}$
- Avalanche Energy Rated

Applications

- General Rectifier
- Output Rectifier in Switching Power Supply & Welder
- FWD for Motor Application

Absolute Maximum Ratings

per diode at $T_C=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter		Ratings	Unit
V_{RRM}	Peak Repetitive Reverse Voltage		1200	V
V_{RWM}	Working Peak Reverse Voltage		1200	V
V_R	DC Blocking Voltage		1200	V
$I_{F(AV)}$	Average Rectified Forward Current	per device at $T_C=120^\circ\text{C}$	8	A
I_{FSM}	Non-repetitive Peak Surge Current		100	A
T_J	Operating Junction Temperature Range		-65~+150	°C
T_{STG}	Storage Temperature Range		-65~+150	°C

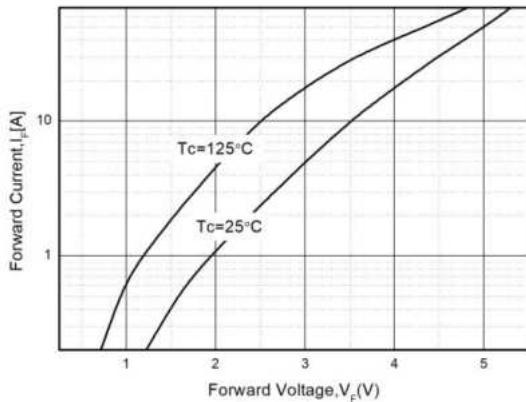
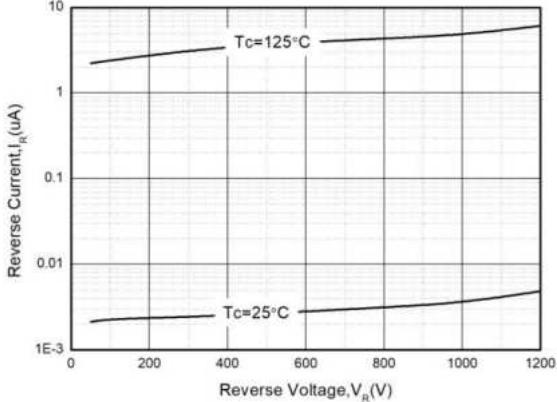
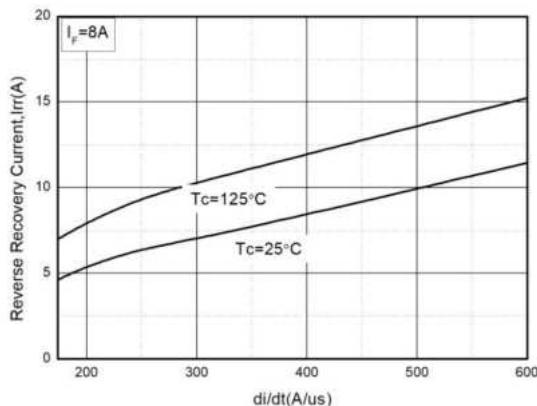
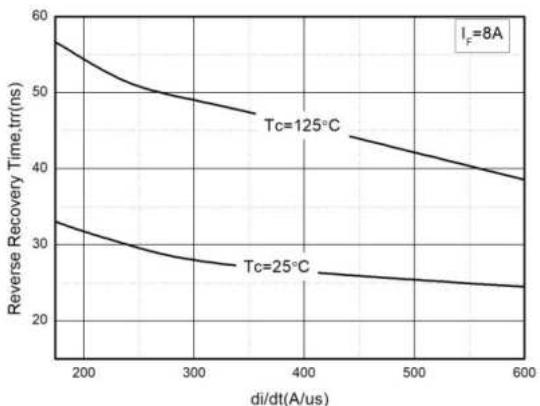
Thermal Characteristics

Symbol	Parameter	Ratings	Unit
$R_{th(J-C)}$	Thermal Resistance, Junction to case	2	°C/W

Electrical Characteristics per diode @ $T_c=25\text{ }^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
V_F	Forward Voltage Drop	$I_F=8\text{A}$	-	3.2	-	V
		$I_F=8\text{A}, T_c=125\text{ }^\circ\text{C}$	-	2.3	-	V
I_R	Reverse Leakage Current	$V_R=1200\text{V}$	-	-	100	μA
t_{rr}	Reverse Recovery Time	$I_F=8\text{A}, \text{di}/\text{dt}=-200\text{A}/\text{us}$	-	32	-	ns
W_{AVL}	Avalanche Energy	$L=5\text{mH}$	-	55	-	mJ

Typical Performance Characteristics

 Fig. 1. Typical Characteristics: V_F vs. I_F

 Fig. 2. Typical Characteristics: V_R vs. I_R

 Fig. 3. Typical Reverse Recovery Time vs. di/dt

 Fig. 4. Typical Reverse Recovery Current vs. di/dt


Package Dimensions
TO-220

(Dimensions in Millimeters)

